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(54) **LIGHT EMITTING DIODE THERMALLY ENHANCED CAVITY PACKAGE AND METHOD OF MANUFACTURE**

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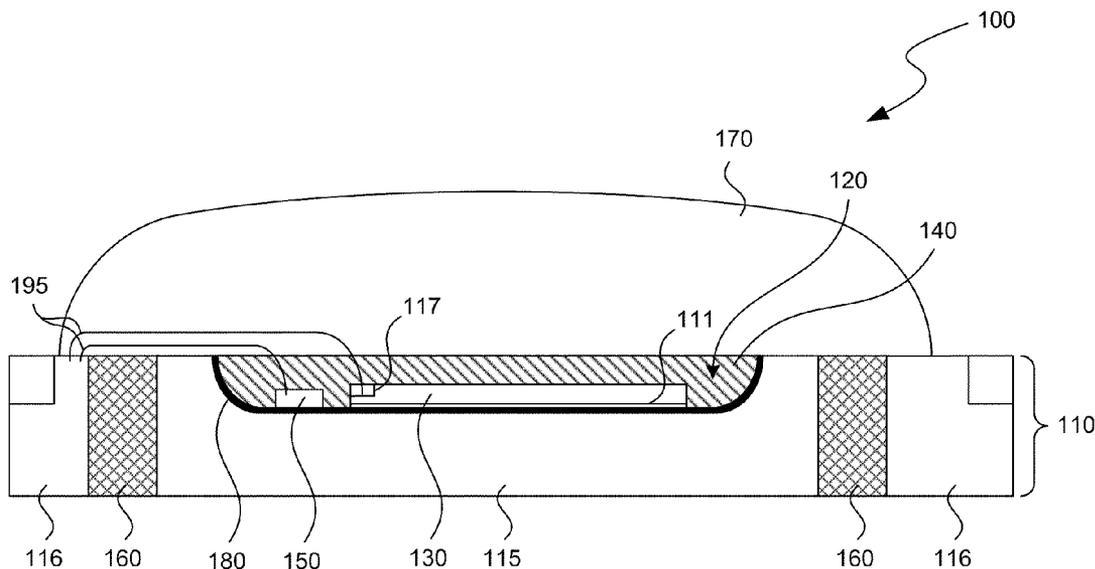
(57) **ABSTRACT**

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Several embodiments of light emitting diode packaging configurations including a substrate with a cavity are disclosed herein. In one embodiment, a cavity is formed on a substrate to contain an LED and phosphor layer. The substrate has a channel separating the substrate into a first portion containing the cavity and a second portion. A filler of encapsulant material or other electrically insulating material is molded in the channel. The first portion can serve as a cathode for the LED and the second portion can serve as the anode.

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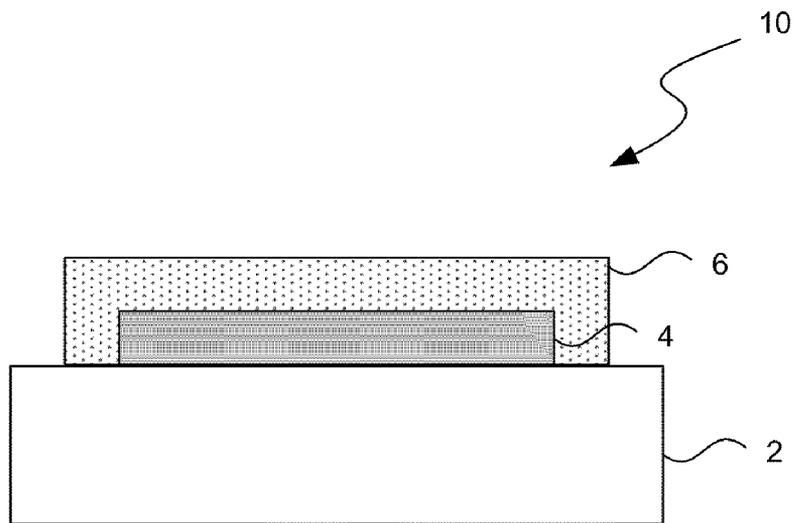


FIG. 1A
(Prior Art)

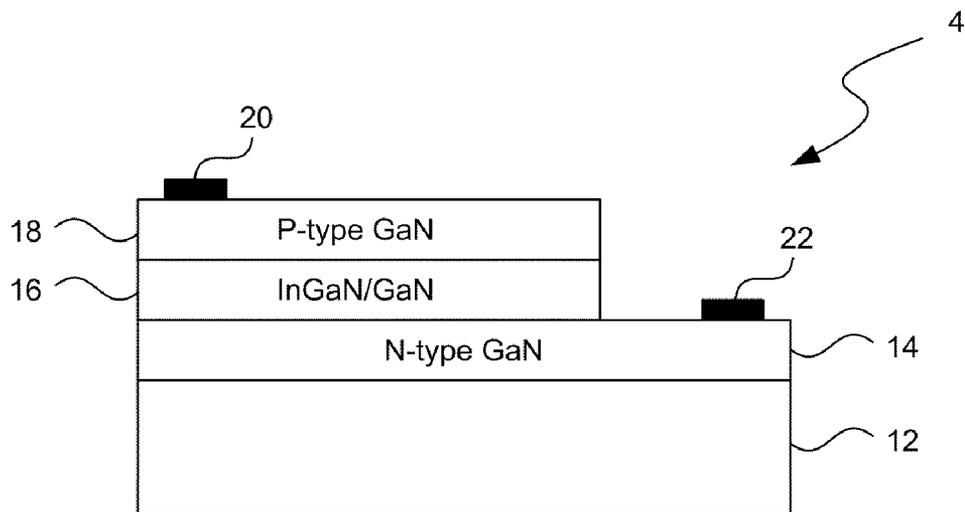


FIG. 1B
(Prior Art)

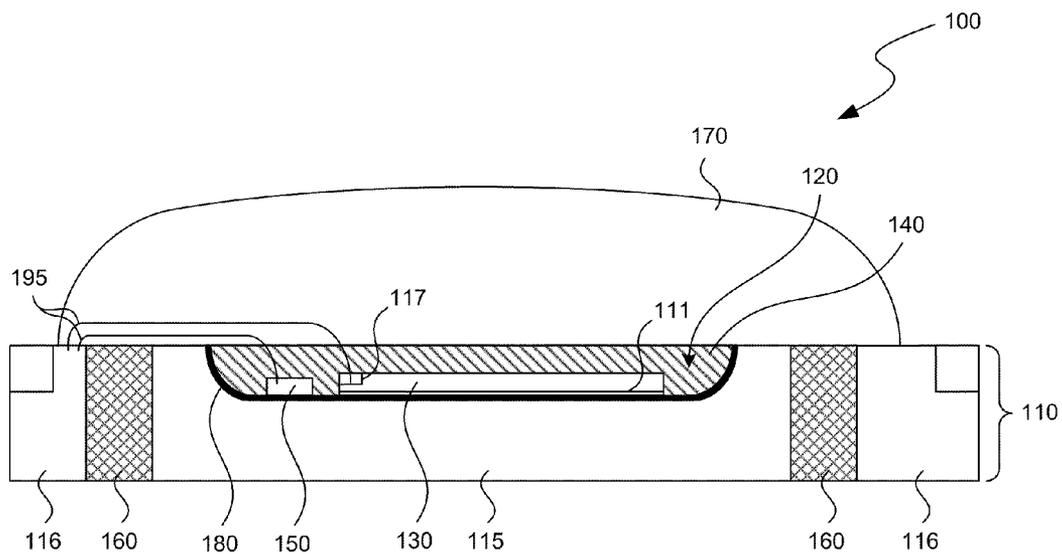


FIG. 2

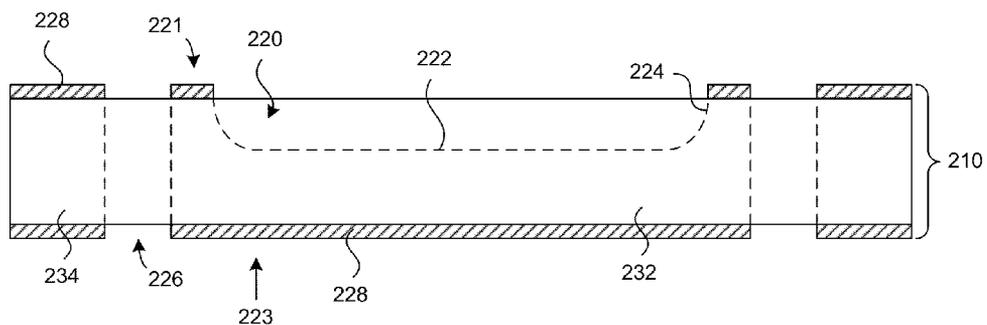


FIG. 3A

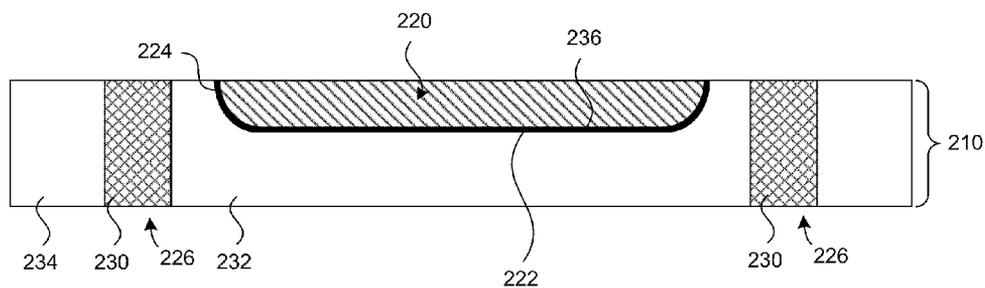


FIG. 3B

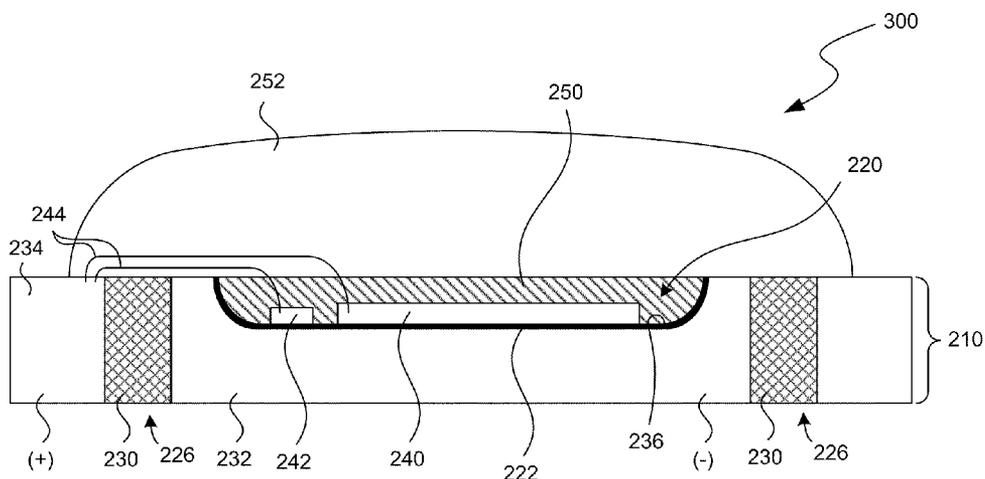


FIG. 3C

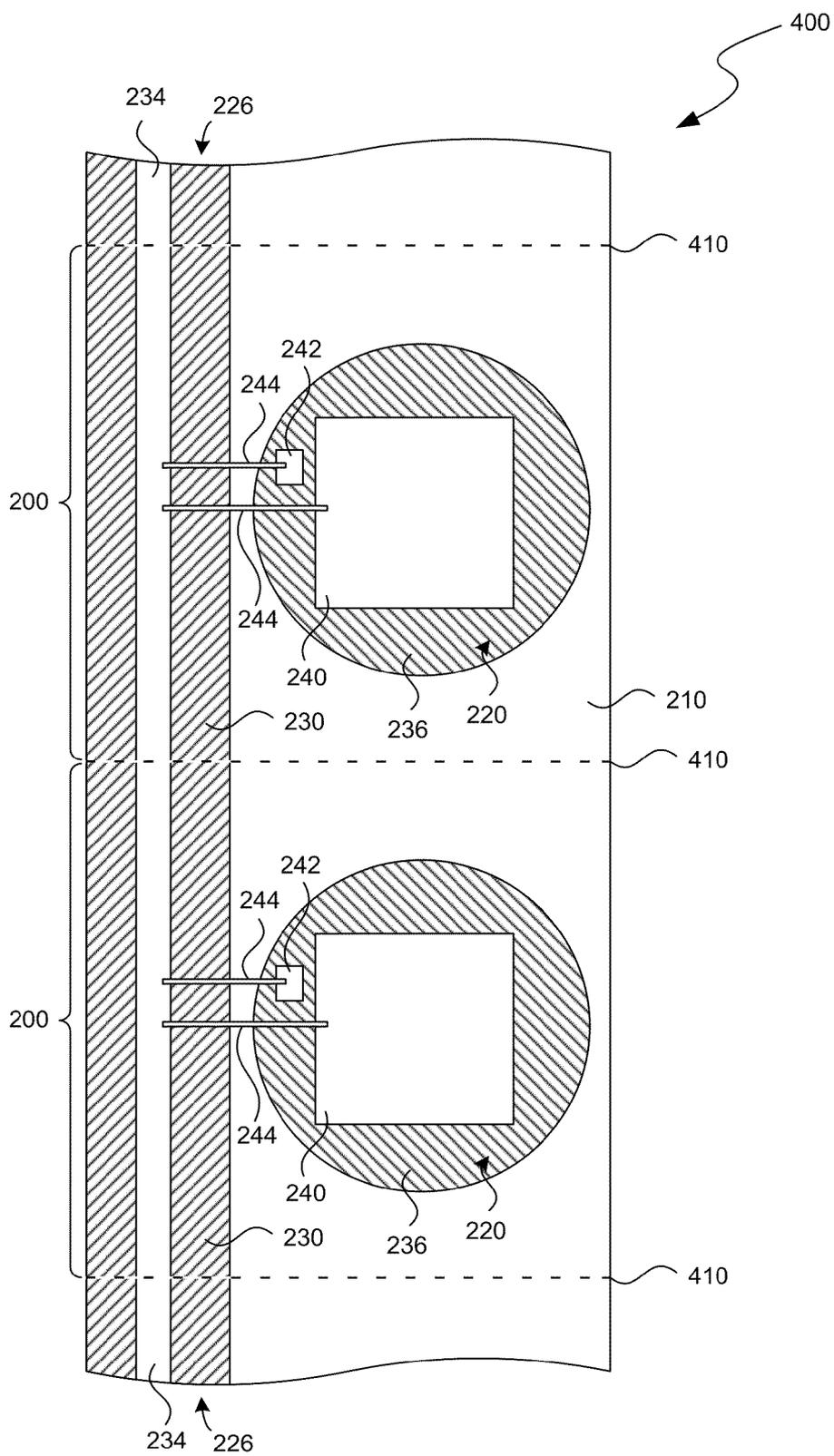


FIG. 4A

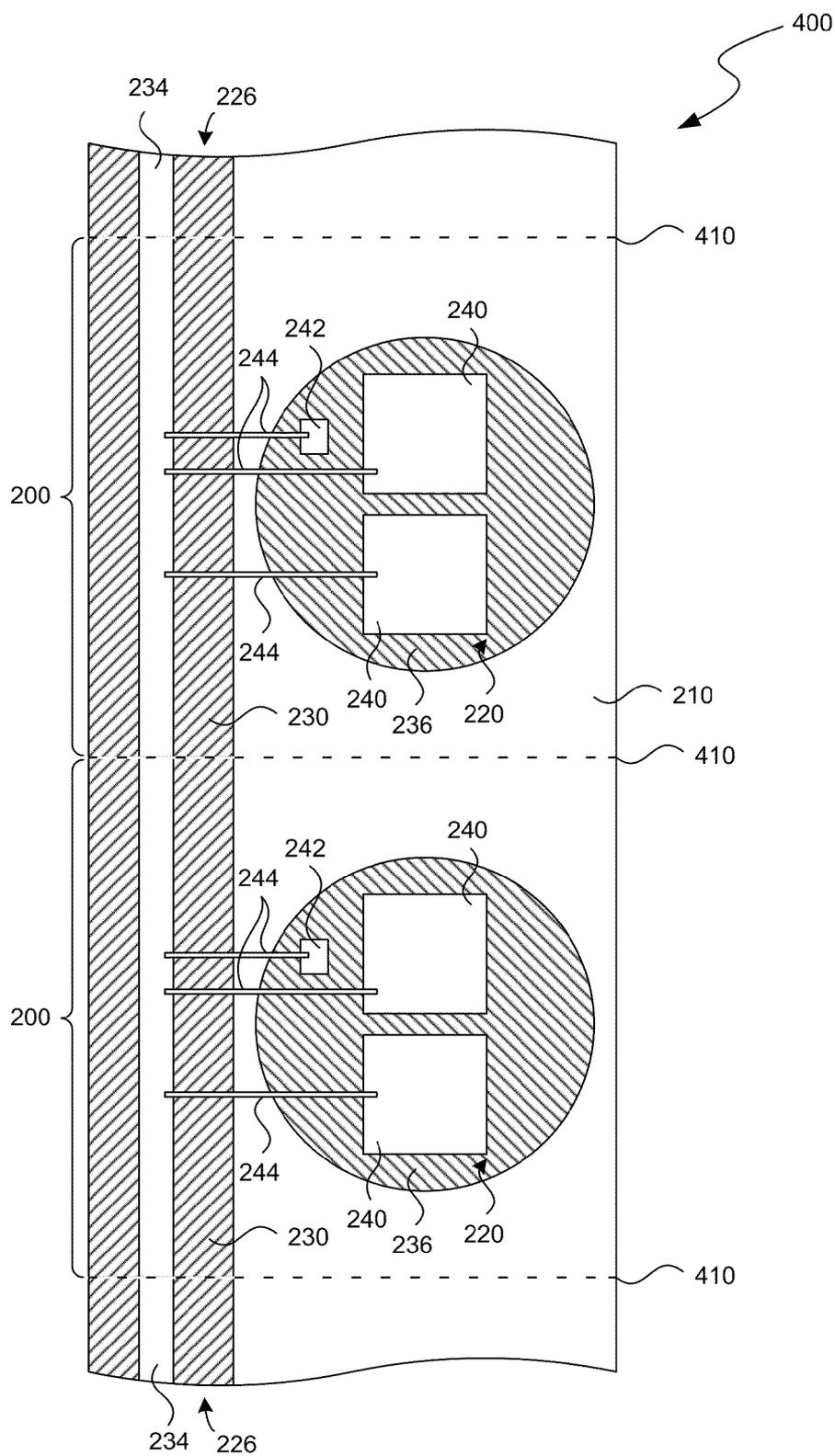


FIG. 4B

**LIGHT EMITTING DIODE THERMALLY
ENHANCED CAVITY PACKAGE AND
METHOD OF MANUFACTURE**

TECHNICAL FIELD

[0001] The present disclosure is related to solid state lighting (SSL) devices and associated methods of operation and manufacture. In particular, the present disclosure is related to light emitting diodes (LEDs) and associated methods of packaging.

BACKGROUND

[0002] Mobile phones, personal digital assistants (PDAs), digital cameras, MP3 players, and other portable electronic devices utilize SSL devices (e.g., white light LEDs) for background illumination. However, true white light LEDs are not available because LEDs typically only emit light at one particular wavelength. For human eyes to perceive the color white, a mixture of wavelengths is needed.

[0003] One conventional technique for emulating white light with LEDs includes depositing a converter material (e.g., a phosphor) on a light emitting material. For example, as shown in FIG. 1A, a conventional LED device **10** includes a support **2** carrying an LED die **4** and a converter material **6** deposited on the LED die **4**. The LED die **4** can include one or more light emitting components. For example, as shown in FIG. 1B, the LED die **4** can include a silicon substrate **12**, N-type gallium nitride (GaN) material **14**, an indium gallium nitride (InGaN) material **16** (and/or GaN multiple quantum wells), and a P-type GaN material **18** on one another in series. The LED die **4** can also include a first contact **20** on the P-type GaN material **18** and a second contact **22** on the N-type GaN material **14**. Referring to both FIGS. 1A and 1B, in operation, the InGaN material **16** of the LED die **4** emits a blue light that stimulates the converter material **6** to emit a light (e.g., a yellow light) at a desired frequency. The combination of the blue and yellow emissions appears white to human eyes if matched appropriately.

[0004] One operational difficulty of the LED device **10** is that the LED die **4** produces a significant amount of heat. The generated heat raises the temperature of the converter material **6**, and thus causes the converter material **6** to emit light at a different frequency than the desired frequency (a phenomenon commonly referred to as “thermal quenching”). As a result, the combined emissions would appear off-white and may reduce the color fidelity of electronic devices. Accordingly, several improvements in managing the thermal load in LED packages may be desirable.

BRIEF DESCRIPTION OF THE DRAWINGS

[0005] FIG. 1A is a schematic cross-sectional diagram of an LED device in accordance with the prior art.

[0006] FIG. 1B is a schematic cross-sectional diagram of an LED die in accordance with the prior art.

[0007] FIG. 2 is a partially schematic cross-sectional view of a microelectronic LED package in accordance with the new technology.

[0008] FIG. 3A is a partially schematic cross-sectional view of a manufacturing process for a microelectronic LED package in accordance with the new technology.

[0009] FIG. 3B is a partially schematic cross-sectional view of a manufacturing process for a microelectronic LED package in accordance with the new technology.

[0010] FIG. 3C is a partially schematic cross-sectional view of a manufacturing process for a microelectronic LED package in accordance with the new technology.

[0011] FIG. 4A is a partially schematic top view of a microelectronic device in accordance with the new technology.

[0012] FIG. 4B is a partially schematic top view of a microelectronic device in accordance with the new technology.

DETAILED DESCRIPTION

[0013] Specific details of several embodiments of the new technology are described below with reference to LEDs and light converter materials including phosphor materials, and associated methods of manufacturing LED assemblies. The term “phosphor” generally refers to a material that emits light when irradiated by energized particles (e.g., electrons and/or photons). A person skilled in the relevant art will understand that the new technology may have additional embodiments and that the new technology may be practiced without several of the details of the embodiments described below with references to FIGS. 2-4B.

[0014] FIG. 2 illustrates an LED package **100** in accordance with several embodiments of the technology. The package **100** includes a conductive substrate **110** with a cavity **120**, an LED **130** in the cavity **120**, and a converter material **140** configured to be irradiated by the LED **130**. The cavity **120** can be depression, such as a “blind cavity,” that extends to an intermediate depth within the substrate **110** without passing completely through the substrate **110**. The package **100** can further include an electrostatic dissipation (ESD) chip **150** and a reflective material **180** lining the cavity **120**. The package **100** can also contain a filler **160** that separates a medial, first portion **115** of the conductive substrate **110** from a lateral, second portion **116** of the substrate **110**. For example, filler **160** can be a dielectric spacer between the first portion **115** and the second portion **116** that electrically isolates the first portion **115** from the second portion **116**. In some embodiments, the package **100** also includes a lens **170** over the components in the cavity **120**. The package **100** can include one or more LEDs **130** in a single cavity **120**. In some embodiments, the cavity **120** is deeper than the thickness of the LED **130** such that the LED fits within the cavity without protruding above the surface of the substrate **110**.

[0015] The conductive substrate **110** can be copper (Cu) or another suitable material that has a high thermal and electrical conductivity, such as aluminum (Al), tungsten (W), stainless steel, and/or suitable substances or alloys. The conductive substrate **110** can also provide mechanical support and rigidity for the package **100**. The substrate **110** can accordingly be a heat sink with a high thermal conductivity to transfer heat from the LED **130** and/or the converter material **140**.

[0016] The package **100** can include a single LED **130** or a plurality of LEDs arranged in an array. The LED **130** can be configured to emit light in the visible spectrum (e.g., from about 565 nm to about 660 nm), in the infrared spectrum (e.g., from about 680 nm to about 970 nm), in the near infrared spectrum (e.g., from about 1050 nm to about 1550 nm), and/or in other suitable spectra. In some embodiments, the LED **130** is made generally similar to the LED die **4** shown in FIG. 1B but instead of the silicon substrate **12**, the LED **130** can have a metallized contact surface at the base of the LED **130** made of copper (Cu), aluminum (Al), tungsten (W), stainless steel, and/or other suitable metal and/or metal alloys, or other electrically conductive materials such as silicon carbide (SiC). The contact surface can be a first lead **111**

for the LED 130. In other embodiments, the N-type GaN material 14 serves as the first lead 111.

[0017] The LED 130 can be surface mounted to the first portion 115 of the substrate 110 in the cavity 120 through the first lead 111. The LED 130 can have a second lead 117 spaced apart from the first lead 111 and connected to the second portion 116 of the substrate 110, for example, through a wirebond 195. The first lead 111 in series with the first portion 115 can be a cathodic lead, and the second lead 117 in series with the second portion 116 can be an anodic lead, or vice-versa. Surface mounting the first lead 111 to the first portion 115 largely eliminates the need for expensive, time-consuming processes required for aligning and connecting very small electrical terminals (e.g., bond-pads) between conventional LEDs and substrates. For example, the positional tolerance of a pair of contacts is related, at least in part, to the size of the contacts in the pair. Aligning two, small contacts requires accurate positioning, while aligning a small contact on a larger surface does not require the same precision. In an embodiment, the first lead 111 comprises the entire contact surface of the LED 130 to provide a large contact surface with high positional tolerance. Because the first portion 115 is electrically isolated from the second portion 116 by the filler 160, a circuit is formed between the first portion 115, the LED 130, and the second portion 116.

[0018] To achieve certain colors of light from the LED 130, a converter material 140 can be used to alter or compliment the color of light that leaves the LED 130. The converter material 140 can be placed in the cavity 120 over the LED 130 such that light from the LED 130 irradiates the phosphor in the converter material 140; the irradiated phosphor then emits light of a certain quality. Alternatively, the converter material 140 can be spaced apart from the LED 130 or in any other location that is irradiated by the LED 130. The lens 170, for example, can be infused with the converter material 140 in a single structure. For example, in one embodiment, the converter material 140 can include a phosphor containing cerium (III)-doped yttrium aluminum garnet (YAG) at a particular concentration for emitting a range of colors from green to yellow and to red under photoluminescence. In other embodiments, the converter material 140 can include neodymium-doped YAG, neodymium-chromium double-doped YAG, erbium-doped YAG, ytterbium-doped YAG, neodymium-cerium double-doped YAG, holmium-chromium-thulium triple-doped YAG, thulium-doped YAG, chromium(IV)-doped YAG, dysprosium-doped YAG, samarium-doped YAG, terbium-doped YAG, and/or other suitable phosphor compositions. The lens 170 can simply transmit the light from the LED 130 and converter material 140, or it can further focus or otherwise alter characteristics of the light.

[0019] The ESD chip 150 can prevent, mitigate, or dissipate static electricity in the LED package 100. The ESD chip 150 can be positioned in the cavity 120 or in any other convenient location.

[0020] The reflective material 180 can comprise silver, gold, or another material with generally high reflectivity and thermal conductivity. The reflective material 180 can line the cavity 120 to reflect light produced by the LED 130 through the converter material 140. The reflected light accordingly increases the output of the LED package 100 rather than being absorbed as heat. The reflective material 180 can be chosen based on its reflective qualities and for the color of light each material reflects. For example, when the surface of the substrate 110 is copper, the reflected light will have some copper

colored components. A silver reflective material 180, however, also reflects light but generally without coloring the light. When a colored light is desired, the reflective material 180 can be gold or copper or another reflective, colored surface.

[0021] FIGS. 3A-3C illustrate processes for manufacturing packaged LEDs in accordance with several embodiments of the present technology. FIG. 3A depicts a substrate 210 that can begin as a single sheet of material such as copper (Cu), aluminum (Al), tungsten (W), or another suitable material. Preferably, the substrate 210 is made of an electrically and/or thermally conductive material as described above. A cavity 220 can be formed in the substrate 210 by an etching process (e.g., wet etch) or another suitable process. The cavity 220 can be a blind cavity extending into the substrate 210 leaving a bottom surface 222 and a sloped perimeter region 224 that can be rounded, angled, or vertical. The etch process can be controlled using a mask 228 covering portions of the substrate 210 that are not to be etched.

[0022] The structure shown in FIGS. 3A-3B can be made with separate top-side and bottom-side processes. For example, the cavity 220 and at least a portion of the channel 226 can be formed in the substrate 210 by a first etch process that removes material from a top-side 221. A second etch process can be performed to remove material from a bottom-side 223 of the substrate 210 at a location aligned with the location of the first etch process to complete the channel 226. The etch process can be a wet etch or another suitable process. In other embodiments, the cavity 220 and channels 226 can be created using separate and/or different processes, such as molding, pressing, grinding, and/or cutting. The processes of making the channels 226 can be used to separate a solid substrate 210 into a first portion 232 and a second portion 234.

[0023] FIG. 3B illustrates a manufacturing process according to further embodiments of the present technology in which a reflective material 236 is formed to line the cavity 222 and a filler 230 is molded in the channels 226. The reflective material 236 can be plated or formed by vapor deposition or by another, suitable method. The filler 230 can be any type of electrically insulating, moldable material to electrically isolate the first portion 232 of the substrate 210 from the second portion 234 and bond the first portion 232 and the second portion 234 together. The substrate 210 and the filler 230 form a composite structure of conductive and non-conductive materials. Additional holes and moldings can be formed into the substrate 210 depending on design considerations and to accommodate a host device.

[0024] FIG. 3C shows a subsequent portion of a manufacturing process according to several embodiments of the present technology in which an LED 240 is placed in the cavity 220 and electrically connected with the first portion 232 of the substrate 210. An ESD component 242 can also be placed in the cavity 220 or in another suitable location to mitigate damage from static electricity, similar to components explained above with respect to LED 130. As explained above, the base of the LED 240 can be electrically conductive or have a conductive contact that electrically couples the LED 240 to the first portion 232 of the substrate 210. The backside of the LED 240 can therefore be surface-mounted to the first portion 232 using a solder paste, copper bonding, or other suitable technique. The LED 240 and the ESD component 242 can also be connected to the second portion 234 through, for example, wirebonds 244 or other electrical connection means. Because the exposed surface of the substrate 210 in

the cavity **220** is generally conductive, the positional tolerance for the LED **240** is relatively high and aligning the LED **240** in the cavity **220** is simple and inexpensive. Also, the conductive nature of the substrate **210** helps to dissipate heat produced by the LED **240**.

[0025] A converter material **250**, such as a phosphor material, can be formed in the cavity **220** or above the cavity **220**. The converter material **250** can include a carrier with phosphor particles on and/or embedded in the carrier. The carrier, for example, can be a thermo-forming resin, silicone, or other suitably transparent material. The cavity **220** provides a convenient recess, or depression into which the phosphor material can be deposited in a single, easy process without having to form a separate dam on the surface of the substrate **210**. Conventional phosphor structures that are built on a flat surface with no cavity generally require a first deposition process to build a dam to hold the phosphor in place, and a second process to fill the dam with the phosphor material. The cavity **220** simplifies and speeds the process by eliminating the need to construct a separate dam. The converter material **250** generally fills the cavity **220** and covers the LED **240**. In other embodiments, the converter material **250** may not completely cover the LED **240**. The converter material **250** can contain any type of phosphor for use with any type of LED **240** to achieve a desired light characteristic. A lens **252** can be constructed over the LED **240** to further focus or alter the light from the LED **240**. The processes of FIGS. 3A-C produce a packaged LED unit **300**.

[0026] FIG. 4A is a partially schematic top view of a strip **400** having a plurality of LED units **300** according to the present technology. Many features of the individual LED units **300** are substantially analogous to features described above with reference to FIGS. 2 and 3A-3C, and can be made using similar manufacturing techniques. Like reference numbers accordingly correspond to like elements in FIGS. 2-4A. The strip **400** includes the substrate **210**, such as a copper substrate, a depression **220** for each LED unit **300**, and the channel **226** defined by an elongated trench near the depression **220**. The channel **226** can be filled with a molded filler **230** other suitable electrical insulator. Each LED unit **300** has at least one LED **240** and an ESD chip **242** placed in the depression **220**. The substrate **210** can be cut along lines **410** to separate the individual LED units **300** from each other, or the substrate **210** can remain intact such that a single device can have multiple individually packaged LED units **300**. The structures and processes described here can be applied in batch to many, similar packages in the strip or wafer.

[0027] FIG. 4B illustrates an alternative embodiment of the LED package **200** in accordance with the present technology. Features of the package **200** are generally similar to features of FIG. 4A. The package **200** can have a substrate **210** with a depression **220** that contains multiple LEDs **240** in the depression **220**. Any suitable number of LEDs **240** can be included in the depression **220**. The LEDs **240** may have different characteristics and may emit light of different frequencies, and the converter material and lens (not shown) can be adjusted as necessary to accommodate the multiple LEDs **240**, including using multiple types of converter materials. Alternatively, the LEDs **240** can be similarly configured. The depression **220** for embodiments including plural LEDs **240** can be larger than the depression **220** in other embodiments. In other embodiments, the depression **220** can be of a uniform size large enough to accommodate a given number of LEDs **240** (e.g., four or five). The uniform size allows the package

200 to include up to the given number of LEDs **240** without requiring a different substrate **210** or reconfiguring any process steps.

[0028] From the foregoing, it will be appreciated that specific embodiments of the invention have been described herein for purposes of illustration, but well-known structures and functions have not been shown or described in detail to avoid unnecessarily obscuring the description of the embodiments of the invention. Where the context permits, singular or plural terms may also include the plural or singular term, respectively. Unless the word “or” is associated with an express clause indicating that the word should be limited to mean only a single item exclusive from the other items in reference to a list of two or more items, then the use of “or” in such a list shall be interpreted as including (a) any single item in the list, (b) all of the items in the list, or (c) any combination of the items in the list.

[0029] Also, it will be appreciated that specific embodiments described above are for purposes of illustration and that various modifications may be made without deviating from the invention. Aspects of the disclosure described in the context of particular embodiments may be combined or eliminated in other embodiments. Further, while advantages associated with certain embodiments of the disclosure may have been described in the context of those embodiments, other embodiments may also exhibit such advantages, but not all embodiments need necessarily exhibit such advantages to fall within the scope of the disclosure. Accordingly, the present invention is not limited to the embodiments described above, which were provided for ease of understanding; rather, the invention includes any and all other embodiments defined by the claims.

I/We claim:

1. A method for forming a packaged light emitting diode (LED), the method comprising:
 - forming a cavity in a first portion of a substrate;
 - separating the first portion of the substrate from the second portion of the substrate;
 - forming a filler in the channel such that the first portion is electrically isolated from the second portion;
 - placing an LED in the cavity;
 - electrically connecting the LED between the first and second portion of the substrate; and
 - forming a phosphor material over the LED in the cavity.
2. The method of claim 1, further comprising:
 - placing an electrostatic dissipation (ESD) chip in the cavity; and
 - electrically connecting the ESD chip and the substrate.
3. The method of claim 1 wherein the substrate comprises a metal substrate.
4. The method of claim 1, further comprising forming a reflective material on an interior region of the cavity.
5. The method of claim 4 wherein the reflective material comprises silver or gold.
6. The method of claim 1 wherein forming the cavity comprises forming a blind cavity with a bottom surface and a sloped surface surrounding the bottom surface.
7. The method of claim 6 wherein the sloped surface comprises a surface inclined at an angle.
8. The method of claim 6 wherein the sloped surface comprises a curved surface.
9. The method of claim 1 wherein the first portion comprises a cathodic lead and the second portion comprises an anodic lead.

10. The method of claim **1** wherein placing the LED in the cavity comprises placing a plurality of LEDs in the cavity.

11. The method of claim **1** wherein forming the cavity comprises etching the material from the substrate.

12. The method of claim **1** wherein forming the channel comprises a first etch that removes material from one side of the substrate to an intermediate depth within the substrate and a second etch that removes material from an opposite side of the substrate in alignment with the first etch.

13. The method of claim **1**, further comprising electrically coupling a base portion of the LED to a bottom surface of the cavity.

14. The method of claim **13** wherein the bottom surface is coated with a reflective material, and wherein the base portion of the LED is electrically coupled to the first portion of the substrate through the reflective material.

15. The method of claim **1** wherein the substrate comprises a copper substrate.

16. A package for a light emitting diode (LED), the package comprising:

a first substrate segment having a surface and a depression extending from the surface into the first substrate segment;

a second substrate segment spaced apart from the first substrate segment;

a spacer between the first and second substrate segments, the spacer electrically isolating the first substrate segment from the second substrate segment;

an LED in the depression, the LED having an anodic component and a cathodic component, wherein the anodic component is electrically connected to the second substrate segment and the cathodic component is electrically connected to the first substrate segment; and

a converter material over at least a portion of the LED.

17. The package of claim **16**, further comprising a reflective material lining at least a portion of the depression.

18. The package of claim **17** wherein the reflective material is at least one of gold or silver.

19. The package of claim **18** wherein the LED comprises: an N-type GaN material;

an InGaN material over the N-type GaN material; and

a P-type GaN material over the InGaN material.

20. The package of claim **19** wherein the N-type GaN material comprises the cathodic component, and wherein the LED is surface-mounted to the first substrate segment with the N-type GaN material electrically connected to the first substrate segment.

21. The package of claim **16** wherein the spacer is electrically insulative.

22. The package of claim **19**, further comprising a conductive base layer under the N-type GaN material, wherein the LED is surface-mounted to the first substrate segment with the conductive base layer electrically connected to the first substrate segment.

23. The package of claim **16** wherein the first and second substrate segments are copper.

24. The package of claim **16** wherein the spacer comprises a filler molded between the first and second substrate segments.

25. The package of claim **16** wherein the conversion material comprises a phosphor material.

26. The package of claim **16**, further comprising a plurality of LEDs in the depression.

27. The package of claim **16**, further comprising an electrostatic dissipation chip in the depression and electrically connected to the second substrate segment.

28. The package of claim **16** wherein:

at least one of the first or second substrate segment includes at least one of silicon (Si), gallium nitride (GaN), aluminum nitride (AlN), copper (Cu), aluminum (Al), tungsten (W), stainless steel (Fe), and silicon carbide (SiC);

the LED includes an N-type gallium nitride (GaN) material, an indium gallium nitride (InGaN) material, and a P-type GaN material on one another in series;

the spacer includes at least one of a polyimide, a solvent-soluble thermoplastic polyimide, a ceramic material, and glass; and

the converter material includes at least one of cerium(III)-doped yttrium aluminum garnet ("YAG"), neodymium-doped YAG, neodymium-chromium double-doped YAG, erbium-doped YAG, ytterbium-doped YAG, neodymium-cerium double-doped YAG, holmium-chromium-thulium triple-doped YAG, thulium-doped YAG, chromium(IV)-doped YAG, dysprosium-doped YAG, samarium-doped YAG, and terbium-doped YAG.

29. A package for a light emitting diode (LED), the package comprising:

a first substrate portion having a depression on a surface, wherein the first substrate portion is metal;

a second substrate portion, wherein the second substrate portion is metal;

an electrically insulative material between the first and second substrate portions;

an LED positioned in the depression, wherein the LED has—

a first contact surface-mounted to a base surface of the depression to electrically connect the first contact to the first substrate portion; and

a second contact electrically connected to the second substrate portion; and

a converter material in the depression over at least a portion of the LED.

30. The package of claim **29** wherein the second contact is wirebonded to the second substrate portion.

31. The package of claim **29** wherein the first substrate portion comprises a cathodic lead for the LED and the second substrate portion comprises an anodic lead for the LED.

32. The package of claim **29**, further comprising a reflective material lining at least a portion of the depression.

33. The package of claim **32** wherein the reflective material comprises gold, silver, or copper.

34. The package of claim **29** wherein the first and second substrate portions comprise copper substrates.

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